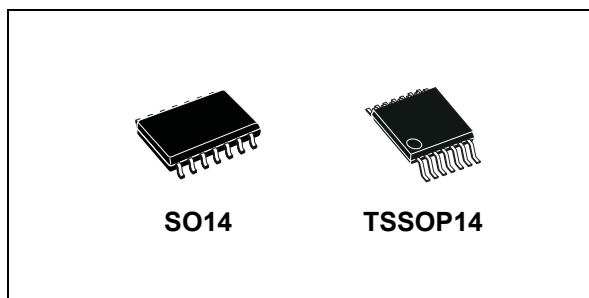


## Quad bus buffer (3-state)

Datasheet - production data



- Balanced propagation delays:  
 $t_{PLH} \cong t_{PHL}$
- Wide operating voltage range:  
 $V_{CC} \text{ (opr)} = 2 \text{ V to } 6 \text{ V}$
- Pin and function compatible with 74 series 126
- ESD performance
  - CDM: 1 kV
  - HBM: 2 kV
  - MM: 200 V

### Features

- High-speed:  
 $t_{PD} = 8 \text{ ns (typ.) at } V_{CC} = 6 \text{ V}$
- Low power dissipation:  
 $I_{CC} = 4 \mu\text{A (max.) at } T_A = 25 \text{ }^\circ\text{C}$
- High noise immunity:  
 $V_{NIH} = V_{NIL} = 28 \% V_{CC} \text{ (min)}$
- Symmetrical output impedance:  
 $I_{OH} = I_{OL} = 6 \text{ mA (min.)}$

### Description

The M74HC126 is a high-speed CMOS quad buffer (3-state) fabricated with silicon gate C<sup>2</sup>MOS technology.

The device requires the 3-state control input, G, to be set high to place the output into high impedance state.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

**Table 1. Device summary**

Order code	Temp. range	Package	Packaging	Marking
M74HC126RM13TR	-55 °C to 125 °C	S014	Tape and reel	74HC126
M74HC126YRM13TR <sup>(1)</sup>	-40 °C to 125 °C	SO14 (automotive grade)		74HC126Y
M74HC126TTR	-55 °C to 125 °C	TSSOP14		HC126
M74HC126YTTR <sup>(1)</sup>	-40 °C to 125 °C	TSSOP14 (automotive grade)		HC126Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

# Contents

- 1      Pin information ..... 3**
- 2      Functional description ..... 4**
- 3      Electrical characteristics ..... 5**
- 4      Package information ..... 10**
  - 4.1    SO14 package information .....11
  - 4.2    TSSOP14 package information ..... 12
- 5      Ordering information ..... 13**
- 6      Revision history ..... 13**

# 1 Pin information

Figure 1. Pin connection and IED logic symbols

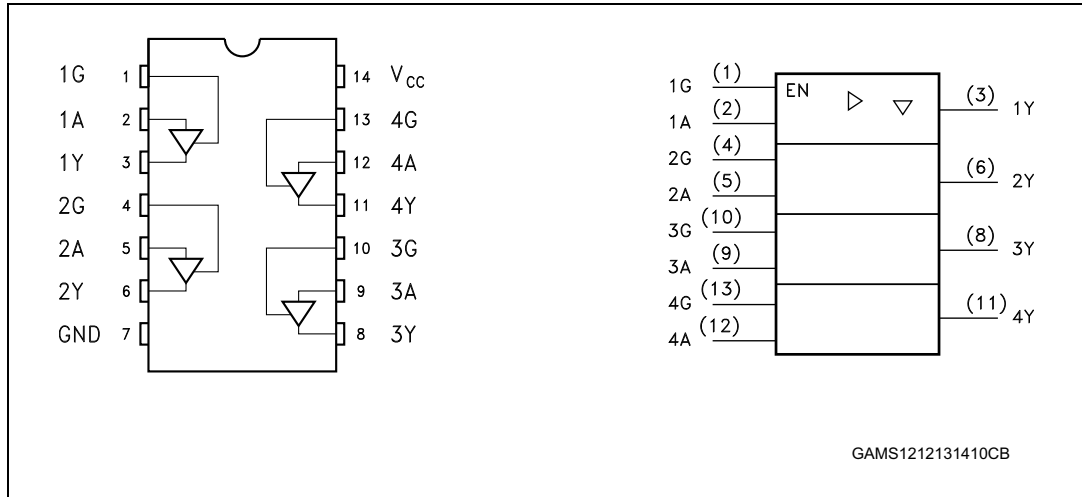


Table 2. Pin description

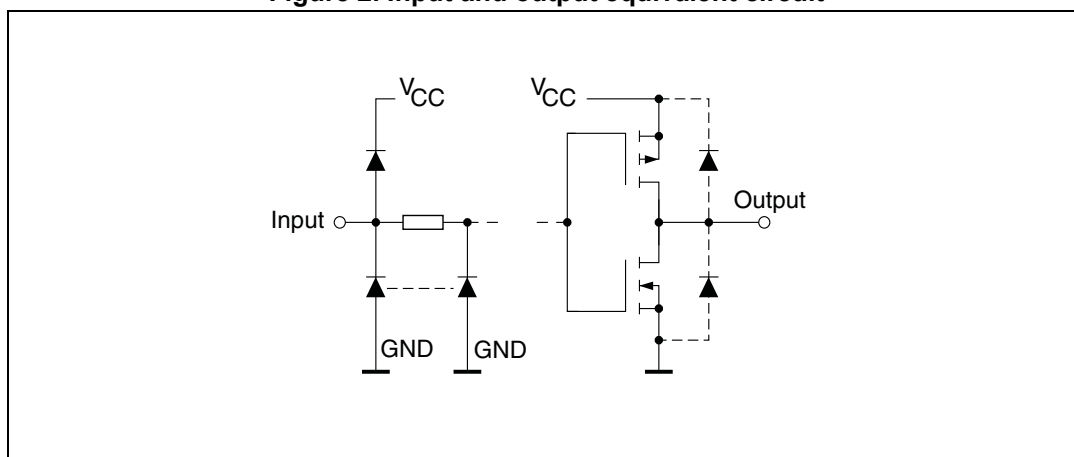
Pin no	Symbol	Name and function
1, 4, 10, 13	1G to 4G	Output enable input
2, 5, 9, 12	1A to 4A	Data inputs
3, 6, 8, 11	1Y to 4Y	Data outputs
7	GND	Ground (0 V)
14	V <sub>CC</sub>	Positive supply voltage

## 2 Functional description

Table 3. Truth table

A	G	Y
X	L	Z
L	H	L
H	H	H

Figure 2. Input and output equivalent circuit



### 3 Electrical characteristics

“Absolute maximum ratings” are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

**Table 4. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	-0.5 to +7	V
$V_I$	DC input voltage	-0.5 to $V_{CC} + 0.5$	
$V_O$	DC output voltage		
$I_{IK}$	DC input diode current	$\pm 20$	mA
$I_{OK}$	DC output diode current		
$I_O$	DC output current	$\pm 35$	
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or ground current	$\pm 70$	
$P_D$	Power dissipation	500 <sup>(1)</sup>	mW
$T_{stg}$	Storage temperature	-65 to +150	°C
$T_L$	Lead temperature (10 sec)	300	

1. 500 mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C

**Table 5. Recommended operating conditions**

Symbol	Parameter	Value	Unit	
$V_{CC}$	Supply voltage	2 to 6	V	
$V_I$	Input voltage	0 to $V_{CC}$		
$V_O$	Output voltage			
$T_{op}$	Operating temperature	-55 to 125	°C	
$t_r, t_f$	Input rise and fall time	$V_{CC} = 2.0\text{ V}$	0 to 1000	ns
		$V_{CC} = 4.5\text{ V}$	0 to 500	
		$V_{CC} = 6.0\text{ V}$	0 to 400	

Table 6. DC specifications

Symbol	Parameter	Test condition		Value						Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25 °C			-40 to 85 °C		-55 to 125 °C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V <sub>IH</sub>	High level input voltage	2.0		1.5			1.5		1.5		V
		4.5		3.15			3.15		3.15		
		6.0		4.2			4.2		4.2		
V <sub>IL</sub>	Low level input voltage	2.0				0.5		0.5		0.5	V
		4.5				1.35		1.35		1.35	
		6.0				1.8		1.8		1.8	
V <sub>OH</sub>	High level output voltage	2.0	I <sub>O</sub> = -20 μA	1.9	2.0		1.9		1.9		V
		4.5	I <sub>O</sub> = -20 μA	4.4	4.5		4.4		4.4		
		6.0	I <sub>O</sub> = -20 μA	5.9	6.0		5.9		5.9		
		4.5	I <sub>O</sub> = -6.0 mA	4.18	4.31		4.13		4.10		
		6.0	I <sub>O</sub> = -7.8 mA	5.68	5.8		5.63		5.60		
V <sub>OL</sub>	Low level output voltage	2.0	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	V
		4.5	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	
		6.0	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	
		4.5	I <sub>O</sub> = 6.0 mA		0.17	0.26		0.33		0.40	
		6.0	I <sub>O</sub> = 7.8 mA		0.18	0.26		0.33		0.40	
I <sub>I</sub>	Input leakage current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			±0.1		±1		±1	μA
I <sub>OZ</sub>	High impedance output leakage current	6.0	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND			±0.5		±5		±10	μA
I <sub>CC</sub>	Quiescent supply current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			4		40		80	μA

**Table 7. AC electrical characteristics**  
(Input  $t_r = t_f = 6$  ns)

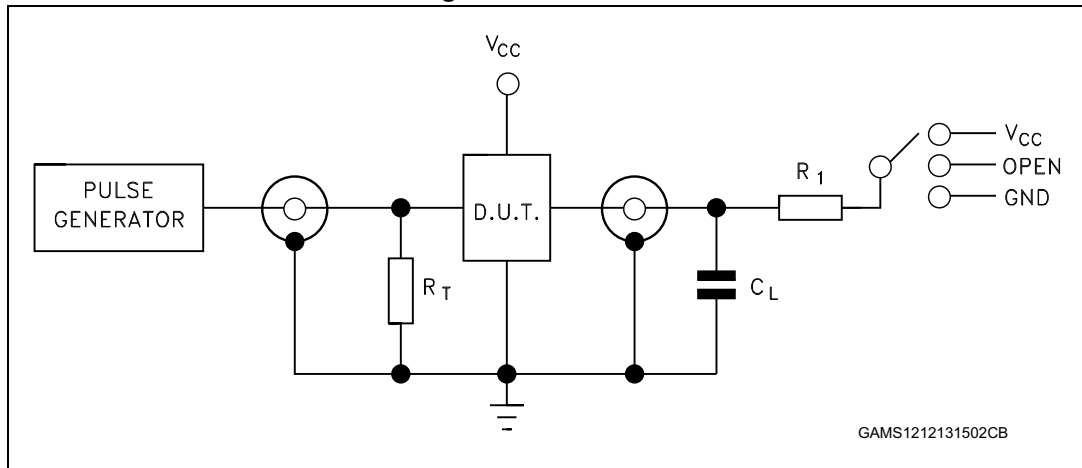
Symbol	Parameter	Test condition			Value								Unit
		$V_{CC}$ (V)	$C_L$ (pF)		$T_A = 25\text{ °C}$			$-40\text{ to }85\text{ °C}$		$-55\text{ to }125\text{ °C}$			
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
$t_{TLH}, t_{THL}$	Output transition time	2.0	50			20	60		75		90	ns	
		4.5			6	12		15		18			
		6.0			5	10		13		15			
$t_{PLH}, t_{PHL}$	Propagation delay time	2.0	50			36	75		95		110	ns	
		4.5			9	15		19		22			
		6.0			8	13		16		19			
		2.0	150			52	105		130		160	ns	
		4.5			13	21		26		32			
		6.0			11	18		22		27			
$t_{PZL}, t_{PZH}$	High impedance output enable time	2.0	50	$R_L = 1\text{ k}\Omega$			36	75		95		110	ns
		4.5				9	15		19		22		
		6.0				8	13		16		19		
		2.0	150				52	105		130		160	ns
		4.5				13	21		26		32		
		6.0				11	18		22		27		
$t_{PLZ}, t_{PHZ}$	High impedance output disable time	2.0	50	$R_L = 1\text{ k}\Omega$			48	80		100		120	ns
		4.5				12	16		20		24		
		6.0				10	14		17		20		

**Table 8. Capacitive characteristics**

Sym	Parameter	Test condition	Value								Unit
		$V_{CC}$ (V)	$T_A = 25\text{ °C}$			$-40\text{ to }85\text{ °C}$		$-55\text{ to }125\text{ °C}$			
			Min	Typ	Max	Min	Max	Min	Max		
$C_{IN}$	Input capacitance	5.0	-	5	10	-	10	-	10	pF	
$C_{PD}$	Power dissipation capacitance <sup>(1)</sup>		-	35	-	-	-	-			

1.  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to test circuit). Average operating current can be obtained by the following equation:  
 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per buffer).

Figure 3. Test circuit



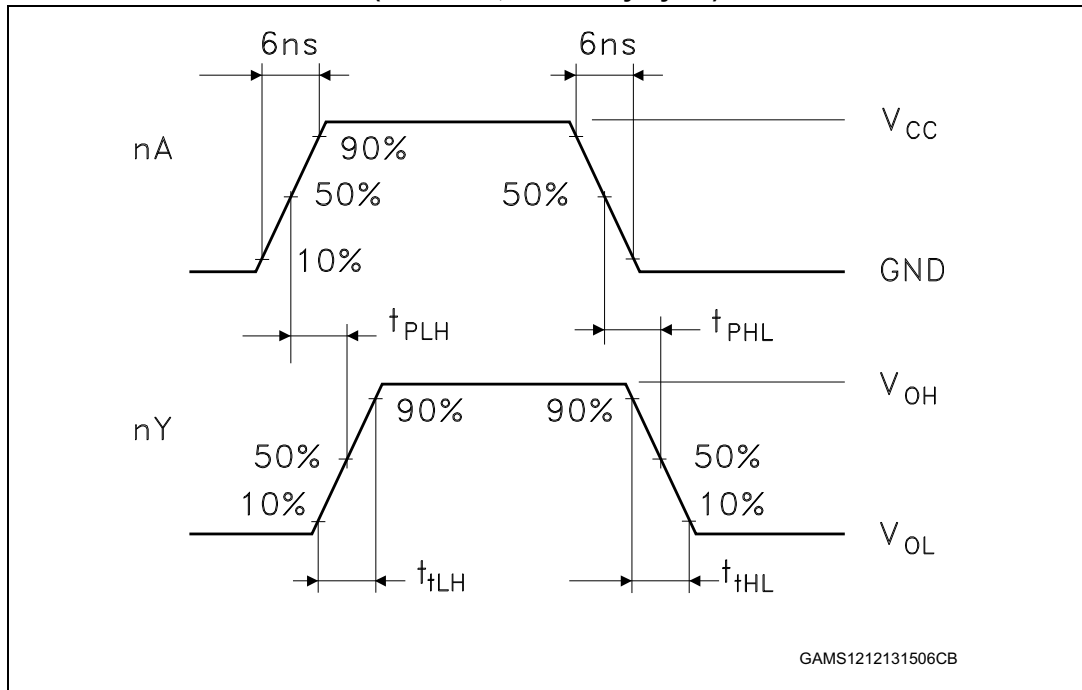
- Legend:  
 $C_L$  = 50 pF/150 pF or equivalent (includes jig and probe capacitance).  
 $R_1$  = 1 k $\Omega$  or equivalent.  
 $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ ).

Table 9. Propagation delay time configuration

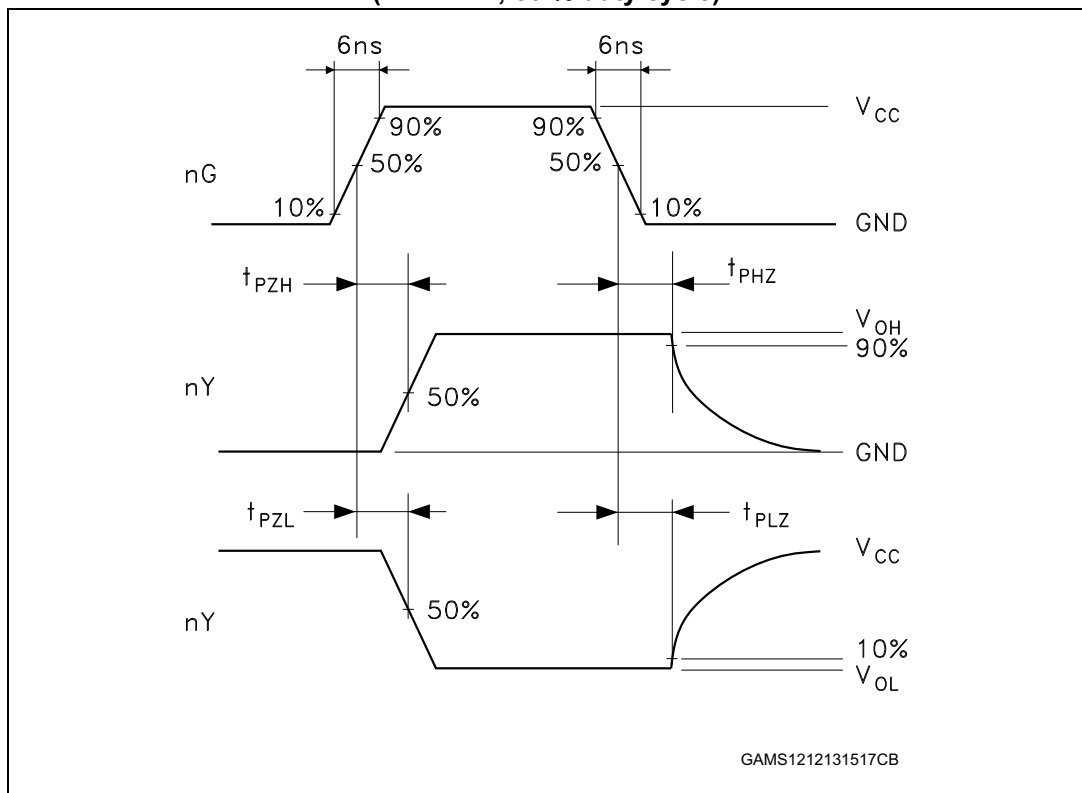
Test	Switch
$t_{PLH}$ , $t_{PHL}$	Open
$t_{PZL}$ , $t_{PLZ}$	$V_{CC}$
$t_{PZH}$ , $t_{PHZ}$	GND



**Figure 4. Waveform 1: propagation delay times**  
(f = 1 MHz; 50 % duty cycle)



**Figure 5. Waveform 2: Output enable and disable times**  
(f = 1 MHz; 50 % duty cycle)



## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

### 4.1 SO14 package information

Figure 6. SO14 package mechanical drawing

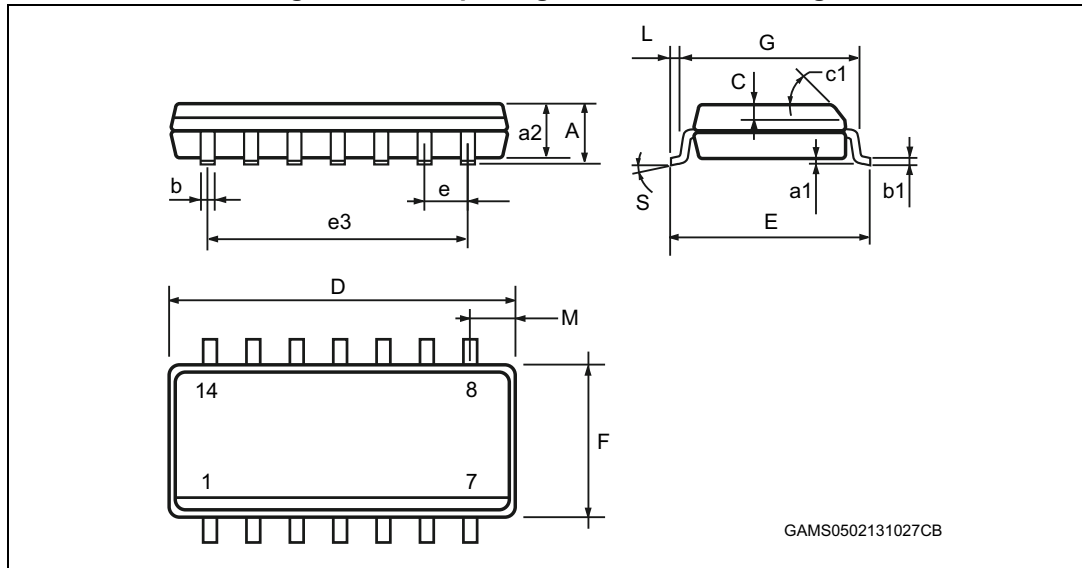


Table 10. SO14 package mechanical data

Ref	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1		45 °			45 °	
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S			8 °			8 °

## 4.2 TSSOP14 package information

Figure 7. TSSOP14 package mechanical drawing

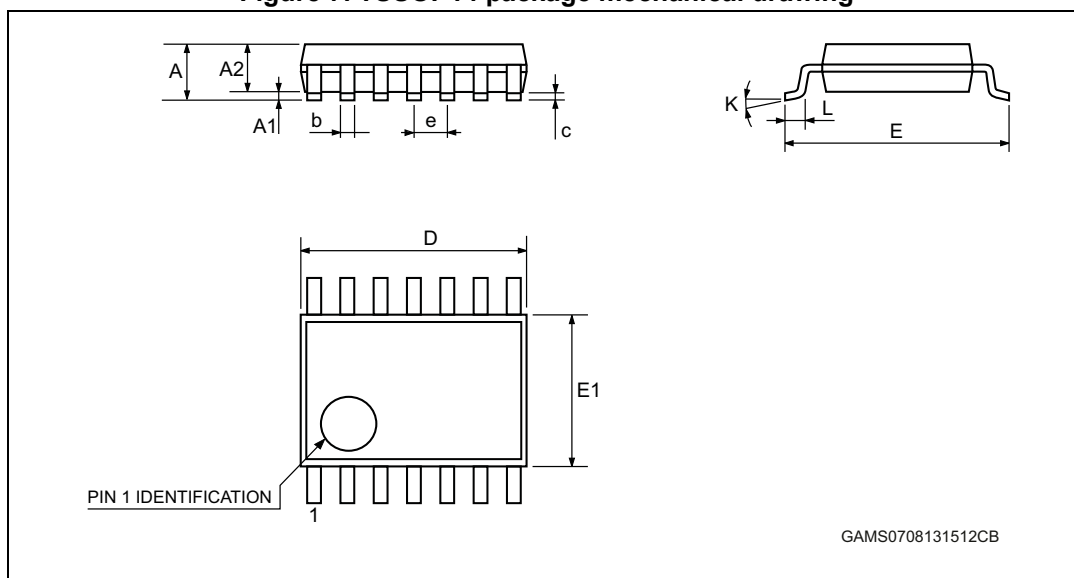


Table 11. TSSOP14 package mechanical data

Ref	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65			0.0256	
K	0 °		8 °	0 °		8 °
L	0.45	0.60	0.75	0.018	0.024	0.030

## 5 Ordering information

Table 12. Order codes

Order code	Temp. range	Package	Packaging	Marking
M74HC126RM13TR	-55 °C to 125 °C	S014	Tape and reel	74HC126
M74HC126YRM13TR <sup>(1)</sup>	-40 °C to 125 °C	SO14 (automotive grade)		74HC126Y
M74HC126TTR	-55 °C to 125 °C	TSSOP14		HC126
M74HC126YTTR <sup>(1)</sup>	-40 °C to 125 °C	TSSOP14 (automotive grade)		HC126Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

## 6 Revision history

Table 13. Document revision history

Date	Revision	Changes
Aug-2001	1	Initial release.
13-Dec-2013	3	Removed DIP14 package <i>Features</i> : added ESD information <i>Table 1: Device summary</i> : updated order codes, added automotive grade order codes, added temperature range and marking details. Added <i>Section 5: Ordering information</i> .

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**ST PRODUCTS ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Buffers & Line Drivers](#) category:*

*Click to view products by [STMicroelectronics](#) manufacturer:*

Other Similar products are found below :

[5962-9217601MSA](#) [634810D](#) [875140G](#) [HEF4022BP](#) [HEF4043BP](#) [NL17SG125DFT2G](#) [NL17SZ126P5T5G](#) [NLU1GT126CMUTCG](#)  
[NLU3G16AMX1TCG](#) [NLV27WZ125USG](#) [MC74HCT365ADTR2G](#) [BCM6306KMLG](#) [54FCT240CTDB](#) [Le87401NQC](#) [Le87402MQC](#)  
[028192B](#) [042140C](#) [051117G](#) [070519XB](#) [065312DB](#) [091056E](#) [098456D](#) [NL17SG07DFT2G](#) [NL17SG17DFT2G](#) [NL17SG34DFT2G](#)  
[NL17SZ07P5T5G](#) [NL17SZ125P5T5G](#) [NLU1GT126AMUTCG](#) [NLV27WZ16DFT2G](#) [5962-8982101PA](#) [5962-9052201PA](#) [74LVC07ADR2G](#)  
[MC74VHC1G125DFT1G](#) [NL17SH17P5T5G](#) [NL17SZ125CMUTCG](#) [NLV17SZ07DFT2G](#) [NLV37WZ17USG](#) [NLVHCT244ADTR2G](#)  
[NC7WZ17FHX](#) [74HCT126T14-13](#) [NL17SH125P5T5G](#) [NLV14049UBDTR2G](#) [NLV37WZ07USG](#) [74VHC541FT\(BE\)](#) [RHFAC244K1](#)  
[74LVC1G17FW4-7](#) [74LVC1G126FZ4-7](#) [BCM6302KMLG](#) [74LVC1G07FZ4-7](#) [74LVC1G125FW4-7](#)